

HD74AC153

Dual 4-Input Multiplexer

REJ03D0251-0200Z (Previous ADE-205-370 (Z)) Rev.2.00 Jul.16.2004

Description

The HD74AC153 is a high-speed dual 4-input multiplexer with common select inputs and individual enable inputs for each section. It can select two lines of data from four sources. The two buffered outputs present data in the true (noninverted) form. In addition to multiplexer operation, the HD74AC153 can act as a function generator and generate any two functions of three variables.

Features

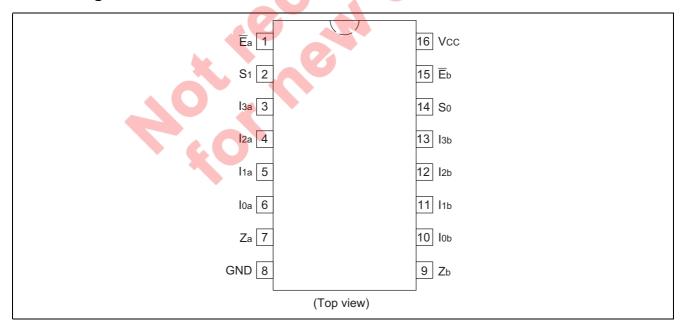
- Outputs Source/Sink 24 mA
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC153FPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74AC153RPEL	SOP-16 pin (JEDEC)	FP-16DNV	RP	EL (2,500 pcs/reel)

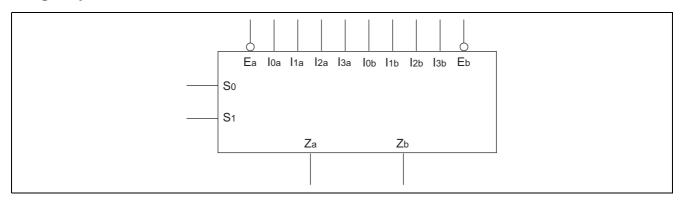
Notes: 1. Please consult the sales office for the above package availability.

2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.

Pin Arrangement



Logic Symbol



Pin Names

I_{0a} to I_{3a}	Side A Data Inputs
I_{0b} to I_{3b}	Side B Data Inputs
S_0, S_1	Common Select Inputs
$\frac{\overline{E}_{a}}{\overline{E}_{b}}$	Side A Enable Input
$\overline{\mathrm{E}}_{\mathrm{b}}$	Side B Enable Input
Z_a	Side A Output
Z_b	Side B Output

Functional Description

The HD74AC153 is a dual 4-input multiplexer. It can select two bits of data from up to four sources under the control of the common Select inputs (S_0, S_1) . The two 4-input multiplexer circuits have individual active-Low Enables $(\overline{E}_a, \overline{E}_b)$ which can be used to strobe the outputs independently. When the Enables $(\overline{E}_a, \overline{E}_b)$ are High, the corresponding outputs (Z_a, Z_b) are forced Low. The HD74AC153 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two Select inputs. The logic equations for the outputs are shown below.

$$\begin{split} Z_a &= \overline{E}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0) \\ Z_b &= \overline{E}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{2b} \bullet S_1 \bullet \overline{S}_0 + I_{3b} \bullet S_1 \bullet S_0) \end{split}$$

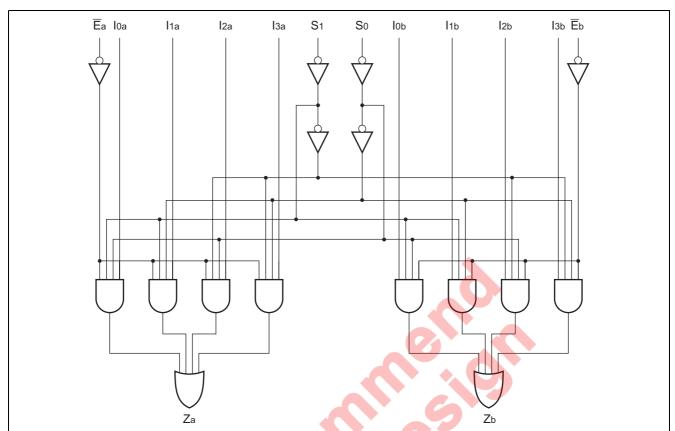
Truth Table

Selec	t Inputs			Input (a or b)	Input (a or b)		
S ₀	S ₁	Ē	I _o	I ₁		I ₃	Z
Χ	X	Н	Х	X	X	X	L
L	L	L	L	X	X	X	L
L	L	L	Н	X	X	X	Н
Н	L	L	X	L	X	X	L
Н	L	L	X	Н	X	X	Н
L	Н	L	X	X	L	X	L
L	Н	L	X	X	Н	X	Н
Н	Н	L	X	X	Х	L	L
Н	Н	L	X	Х	X	Н	Н

H : High Voltage LevelL : Low Voltage Level

X: Immaterial

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	–0.5 to 7	V	
DC input diode current	I _{IK}	-20	mA	$V_1 = -0.5V$
		20	mA	$V_1 = Vcc+0.5V$
DC input voltage	V _I	-0.5 to Vcc+0.5	V	
DC output diode current	I _{ok}	-50	mA	$V_{O} = -0.5V$
Y & O		50	mA	$V_O = Vcc+0.5V$
DC output voltage	V _o	-0.5 to Vcc+0.5	V	
DC output source or sink current	Io	±50	mA	
DC V _{CC} or ground current per output pin	I_{CC}, I_{GND}	±50	mA	
Storage temperature	Tstg	-65 to +150	°C	

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	2 to 6	V	
Input and output voltage	V _I , V _O	0 to V _{CC}	V	
Operating temperature	Та	-40 to +85	°C	
Input rise and fall time	tr, tf	8	ns/V	V _{CC} = 3.0V
(except Schmitt inputs)				V _{CC} = 4.5 V
V_{IN} 30% to 70% V_{CC}				V _{CC} = 5.5 V

DC Characteristics

Item	Sym- bol	Vcc (V)	Ta = 25°C			–40 to 5°C	Unit	Condition	
			min.	typ.	max.	min.	max.		
Input Voltage	V _{IH}	3.0	2.1	1.5		2.1	—	V	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$
		4.5	3.15	2.25		3.15	_		
		5.5	3.85	2.75		3.85	_		
	V _{IL}	3.0	—	1.50	0.9	_	0.9		$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$
		4.5	_	2.25	1.35	_	1.35		
		5.5	_	2.75	1.65	_	1.65		
Output voltage	V_{OH}	3.0	2.9	2.99	_	2.9	_	V	$V_{IN} = V_{IL}$ or V_{IH}
		4.5	4.4	4.49	_	4.4	_		$I_{OUT} = -50 \mu A$
		5.5	5.4	5.49	_	5.4	_		
		3.0	2.58	_	_	2.48	_		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -12 \text{ mA}$
		4.5	3.94	_	_	3.80	_		$I_{OH} = -24 \text{ mA}$
		5.5	4.94	_	_	4.80	_		$I_{OH} = -24 \text{ mA}$
	V _{OL}	3.0	_	0.002	0.1	_	0.1		$V_{IN} = V_{IL}$ or V_{IH}
		4.5	_	0.001	0.1	_	0.1		I _{OUT} = 50 μA
		5.5	_	0.001	0.1	_	0.1		
		3.0	_	_	0.32	_	0.37		$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 12 \text{ mA}$
		4.5	_	_	0.32	- 4	0.37		$I_{OL} = 24 \text{ mA}$
		5.5	_	_	0.32	-	0.37		$I_{OL} = 24 \text{ mA}$
Input leakage	I _{IN}	5.5	_	_	±0.1	-	±1.0	μΑ	V _{IN} = V _{CC} or GND
current									
Dynamic output	I _{OLD}	5.5	_	_		86		mΑ	V _{OLD} = 1.1 V
current*	I _{OHD}	5.5	_	_		-75		mΑ	V _{OHD} = 3.85 V
Quiescent supply current	I _{cc}	5.5	_	7	8.0		80	μΑ	$V_{IN} = V_{CC}$ or ground

^{*}Maximum test duration 2.0 ms, one output loaded at a time.

AC Characteristics: HD74AC153

		•	Ta = +25°C C _L = 50 pF			Ta = -40 °C to $+85$ °C C _L = 50 pF		
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Propagation delay	t _{PLH}	3.3	1.0	9.5	15.0	1.0	17.5	ns
S_n to Z_n		5.0	1.0	6.5	11.0	1.0	12.5	
Propagation delay	t _{PHL}	3.3	1.0	8.5	14.5	1.0	16.5	ns
S_n to Z_n	`	5.0	1.0	6.5	11.0	1.0	12.0	
Propagation delay	t _{PLH}	3.3	1.0	8.0	13.5	1.0	16.0	ns
\overline{E}_n to Z_n		5.0	1.0	5.5	9.5	1.0	11.0	
Propagation delay	t _{PHL}	3.3	1.0	7.0	11.0	1.0	12.5	ns
\overline{E}_n to Z_n		5.0	1.0	5.0	8.0	1.0	9.0	
Propagation delay	t _{PLH}	3.3	1.0	7.5	12.5	1.0	14.5	ns
I_n to Z_n		5.0	1.0	5.5	9.0	1.0	10.5	
Propagation delay	t _{PHL}	3.3	1.0	7.0	11.5	1.0	13.0	ns
I_n to Z_n		5.0	1.0	5.0	8.5	1.0	10.0	

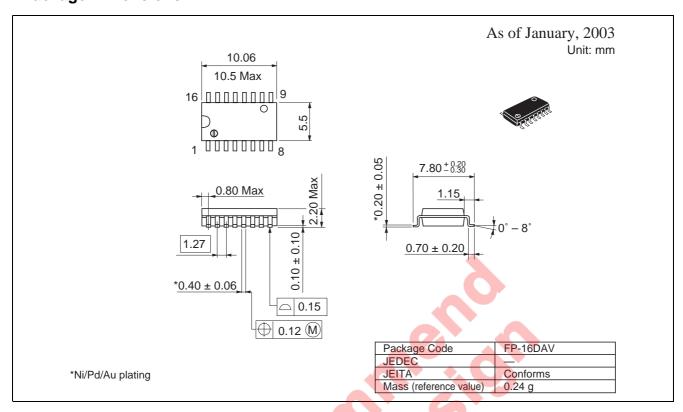
Note: 1. Voltage Range 3.3 is 3.3 V \pm 0.3 V Voltage Range 5.0 is 5.0 V \pm 0.5 V

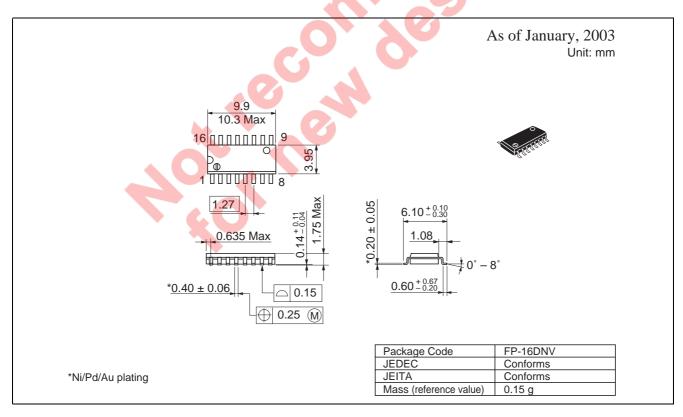
Capacitance

Item	Symbol	Тур	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{CC} = 5.5 V
Power dissipation capacitance	C _{PD}	65.0	pF	V _{CC} = 5.0 V



Package Dimensions





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